

Innovating Energy Technology

2MBI225VX-170-50

IGBT Modules

Power Module (V series) 1700V / 225A / 2-in-1 package

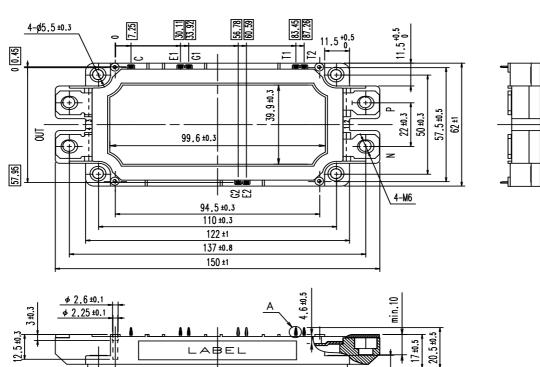
Features

Low V_{CE(sat)} Low Inductance Module structure Solderless press-fit terminals

Applications

Inverter for Motor Drives, AC and DC Servo Drives Uninterruptible Power Supply Systems, Wind Turbines, PV Power Conditioning Systems

■ Outline drawing (Unit : mm)



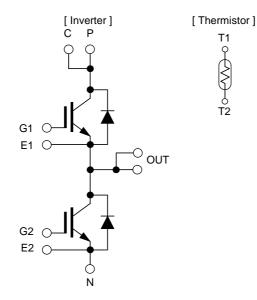
Τ1

NOTE) MARKED SIDE WITH A TOLERANCE OF 4 00.5

Weight: 350g (typ.)

6.5±0.5

Equivalent Circuit





IGBT Modules

■ Absolute Maximum Ratings (at T_c= 25°C unless otherwise specified)

Items		Symbols	Conditions		Maximum Ratings	Units
Collector-Emitter voltage		V _{CES}			1700	V
Gate-Emitter voltage		V _{GES}			±20	V
		I	Continuous	T _C =25°C	300	
Collector current		Ι _C	Continuous	$T_c=100^{\circ}C$	225	
		l _c pulse	1ms		450	A
		-I _C			225	
		-I _C pulse	1ms		450	
Collector power dissipation		P _C	1 device		1500	W
Junction temperature		Tj			175	
Operating junction temperature		T _{jop}	T _{jop}		150	°C
(under switching conditions)						
Case temperature		T _c			125	
Storage temperature		T _{stg}			-40 ~ 125	
Isolation	between terminal and copper base (*1)	V	AC: 1min		2400	VAC
voltage	between thermistor and others (*2)	V _{iso}	AC: 1min.		3400	VAC
Screw	Mounting (*3)	-			3.5	Nm
Torque	Terminals (*4)	-			4.5	

(*1) All terminals should be connected together during the test.

(*2) Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

(*3) Recommendable Value : 2.5-3.5 Nm (M5)

(*4) Recommendable Value : 3.5-4.5 Nm (M6)



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IGBT Modules

■ Electrical characteristics (at T _j =	25°C unless otherwise specified)
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ltomo	Symbols	Conditiono		Characteristics			Lin:4a	
Items	Symbols	Conditions		min.	typ.	max.	Units	
Zero gate voltage Collector current	I _{CES}	V _{GE} =0V, V _{CE} =1700V		-	-	3.0	mA	
Gate-Emitter leakage current	I _{GES}	$V_{CE}=0V, V_{GE}=\pm 20V$		-	-	600	nA	
Gate-Emitter threshold voltage	$V_{\text{GE(th)}}$	V _{CE} =20V, I _C =2	225mA	6.0	6.5	7.0	V	
	N/		T _j =25°C	-	2.35	2.80	- V	
	V _{CE(sat)} (terminal)		T _j =125°C	-	2.80	-		
Collector-Emitter	(terminal)	$V_{GE} = 15V$	T _j =150°C	-	2.85	-		
saturation voltage	V _{CE(sat)} (chip)	I _C = 225A	T _j =25°C	-	2.00	2.45		
			T _j =125°C	-	2.45	-		
			T _j =150°C	-	2.50	-		
Internal gate resistance	R _{G(int)}	-		-	3.33	-	Ω	
Input capacitance	C _{ies}	V _{CE} =10V, V _{GE} :	=0V, f=1MHz	-	23	-	nF	
	t _{on}			-	900	-		
Turn-on time	t _r	V _{CC} = 900V	V _{CC} = 900V	I _C = 225A	-	450	-	
	t _{r(i)}	$V_{GE} = \pm 15V$	R _G = 6.8Ω	-	100	-	nsec	
Turn-off time	t _{off}	L _s = 80nH		-	1050	-		
	t _f	-		-	80	-		
			T _j =25°C	-	2.15	2.60		
	V _F		T _j =125°C	-	2.35	-	- V	
	(terminal)	V _{GE} = 0V I _F = 225A	T _j =150°C	-	2.35	-		
Forward on voltage	V _F (chip)		T _j =25°C	-	1.80	2.25		
			T _i =125°C	-	2.05	-		
			T _i =150°C	-	2.00	-		
Reverse recovery time	t _{rr}	I _F = 225A		-	200	-	nsec	
Thermistor Resistance		T=25°C		-	5000	-	Ω	
memilision Resistance		T=100°C		465	495	520		
Thermistor B value	В	T=25/50°C		3305	3375	3450	K	

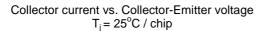
5. Thermal resistance characteristics

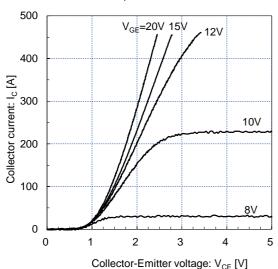
Items	Symbols	Conditions	Characteristics			Units	
items			min.	typ.	max.	Units	
Thermal resistance	R	IGBT	-	-	0.12		
(1device)	R _{th(j-c)}	FWD	-	-	0.20	°C/W	
Contact thermal resistance (1device) (*1)	$R_{th(c-f)}$	with thermal compound	-	0.0167	-	0/11	

(*1) This is the value which is defined mounting on the additional cooling fin with thermal compound.

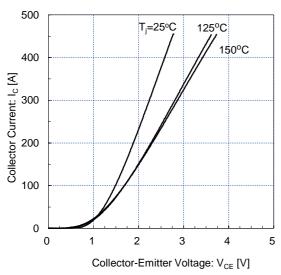


IGBT Modules

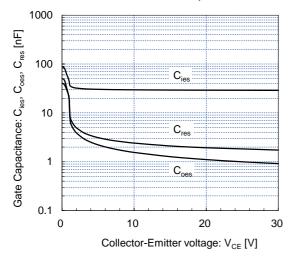




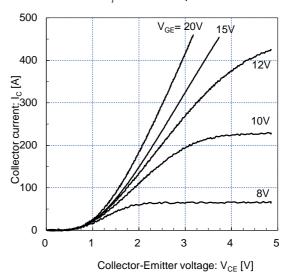




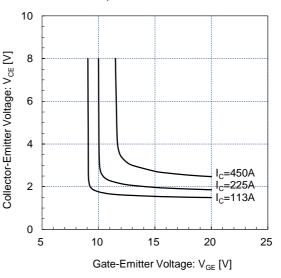


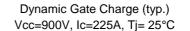


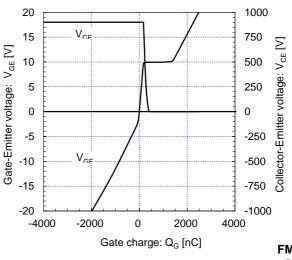




Collector-Emitter voltage vs. Gate-Emitter voltage $T_i = 25^{\circ}C / chip$





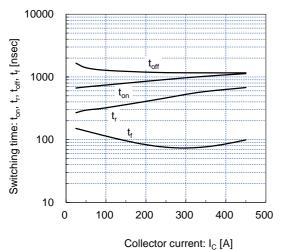




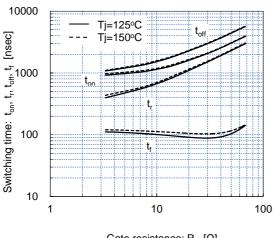
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IGBT Modules

Switching time vs. Collector current (typ.) Vcc=900V, VGE=±15V, Rg=6.8Ω, Tj=25°C

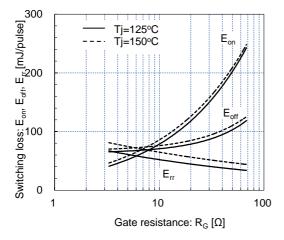


Switching time vs. Gate resistance (typ.) /cc=900V, Ic=225A, VGE=±15V, Tj=125°C, 150°(

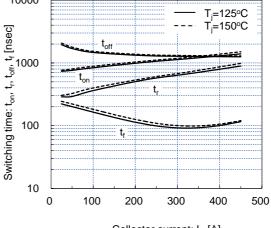


Gate resistance: $R_{G}\left[\Omega\right]$

Switching loss vs. Gate resistance (typ.) /cc=900V, Ic=225A, VGE=±15V, Tj=125°C, 150°(

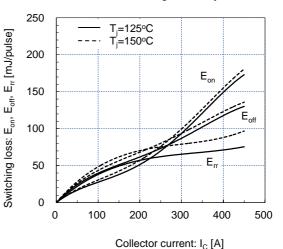


Switching time vs. Collector current (typ.) Vcc=900V, VGE=±15V, Rg=6.8Ω, Tj=125°C, 150°C

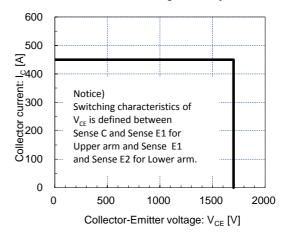


Collector current: I_C [A]

Switching loss vs. Collector current (typ.) Vcc=900V, VGE=±15V, Rg=6.8Ω, Tj=125°C, 150°C

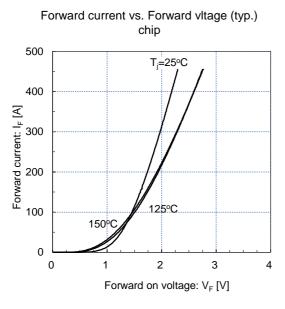


Reverse bias safe operating area (max.) +VGE=15V, -VGE=15V, Rg=6.8Ω, Tj=150°C





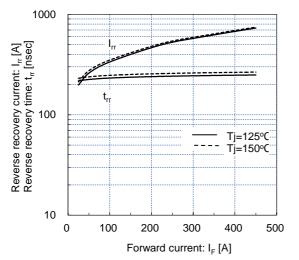
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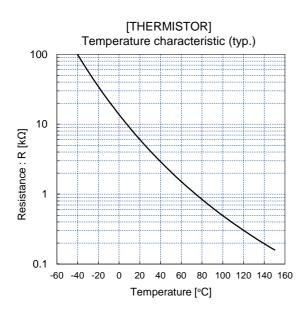


Vcc=900V, VGE=±15V, Rg=6.8Ω, Tj=25°C 10000 Reverse recovery current: I_n [A] Reverse recovery time: t_n [nsec] 00 00 l_{rr} t, 10 0 100 200 300 400 500 Forward current: I_F [A]

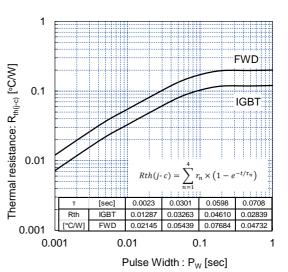
Reverse recovery characteristics (typ.)

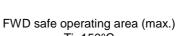
Reverse Recovery Characteristics (typ.) Vcc=900V, VGE=±15V, Rg=6.8Ω, Tj=125°C,150°C

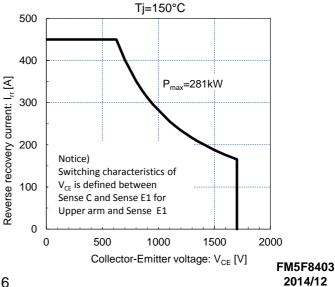




Transient Thermal Resistance (max.)









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